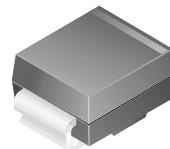


Transient Voltage Suppressors SMBJ5V0(C)A - SMBJ170(C)A

Features

- Glass passivated junction.
- 600W Peak Pulse Power capability on 10/1000 μ s waveform.
- Excellent clamping capability.
- Low incremental surge resistance.
- Fast response time; typically less than 1.0 ps from 0 volts to BV for unidirectional and 5.0 ns for bidirectional.
- Typical I_R less than 1.0 μ A above 10V.



SMB/DO-214AA

COLOR BAND DENOTES CATHODE
ON UNIDIRECTIONAL DEVICES ONLY.
NO COLOR BAND ON BIDIRECTIONAL
DEVICES.

DEVICES FOR BIPOLAR APPLICATIONS

- Bidirectional types use CA suffix.
- Electrical Characteristics apply in both directions.

600 Watt Transient Voltage Suppressors

Absolute Maximum Ratings*

$T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
P_{PPM}	Peak Pulse Power Dissipation on 10/1000 μ s waveform	600	W
I_{PPM}	Peak Pulse Current on 10/1000 μ s waveform	see table	A
I_{FSM}	Non-repetitive Peak Forward Surge Current superimposed on rated load (JEDEC method) (Note 1)	100	A
T_{stg}	Storage Temperature Range	-55 to +150	$^\circ\text{C}$
T_J	Operating Junction Temperature	+ 150	$^\circ\text{C}$

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Note 1: Measured on 8.3 ms single half-sine wave or equivalent square wave; Duty cycle = 4 pulses per minute maximum.

Transient Voltage Suppressors

(continued)

Electrical Characteristics

T_A = 25°C unless otherwise noted

Uni-directional Bi-directional (C) Device	Part Marking*	Reverse Stand-off Voltage V _{RWM} (V)	Breakdown Voltage V _{BR} (V)		Test Current I _T (mA)	Clamping Voltage @ I _{PPM} V _C (V)	Peak Pulse Current I _{PPM} (A)	Reverse Leakage @ V _{RWM} I _R (uA)**
			min	max				
SMBJ5V0(C)A	KE	5.0	6.40	7.0	10	9.2	65.2	800
SMBJ6V0(C)A	KG	6.0	6.67	7.37	10	10.3	58.3	800
SMBJ6V5(C)A	KK(AK)	6.5	7.22	7.98	10	11.2	53.6	500
SMBJ7V0(C)A	KM	7.0	7.78	8.60	10	12.0	50.0	200
SMBJ7V5(C)A	KP(AP)	7.5	8.33	9.21	1	12.9	46.5	100
SMBJ8V0(C)A	KR(AR)	8.0	8.89	9.83	1	13.6	44.1	50
SMBJ8V5(C)A	KT(AT)	8.5	9.44	10.4	1	14.4	41.7	20
SMBJ9V0(C)A	KV(AV)	9.0	10.0	11.1	1	15.4	39.0	10
SMBJ10(C)A	KX(AX)	10	11.1	12.8	1	17.0	35.3	5
SMBJ11(C)A	KZ	11	12.2	13.5	1	18.2	33.0	5
SMBJ12(C)A	LE(BE)	12	13.3	14.7	1	19.9	30.2	5
SMBJ13(C)A	LG	13	14.4	15.9	1	21.5	27.9	5
SMBJ14(C)A	LK(BK)	14	15.6	17.2	1	23.2	25.9	5
SMBJ15(C)A	LM(BM)	15	16.7	18.5	1	24.4	24.6	5
SMBJ16(C)A	LP(LM)	16	17.8	19.7	1	26.0	23.1	5
SMBJ17(C)A	LR	17	18.9	20.9	1	27.6	21.7	5
SMBJ18(C)A	LT(BT)	18	20.0	22.1	1	29.2	20.5	5
SMBJ20(C)A	LV	20	22.2	24.5	1	32.4	18.5	5
SMBJ22(C)A	LX(BX)	22	24.4	26.9	1	35.5	16.9	5
SMBJ24(C)A	LZ(BZ)	24	26.7	29.5	1	38.9	15.4	5
SMBJ26(C)A	ME(CE)	26	28.9	31.9	1	42.1	14.3	5
SMBJ28(C)A	MG	28	31.1	34.4	1	45.4	13.2	5
SMBJ30(C)A	MK(CK)	30	33.3	36.8	1	48.4	12.4	5
SMBJ33(C)A	MM(CM)	33	36.7	40.6	1	53.3	11.3	5
SMBJ36(C)A	MP(CP)	36	40.0	44.2	1	58.1	10.3	5
SMBJ40(C)A	MR(CR)	40	44.4	49.1	1	64.5	9.3	5
SMBJ43(C)A	MT(CT)	43	47.8	52.8	1	69.4	8.6	5
SMBJ45(C)A	MV	45	50.0	55.3	1	72.7	8.3	5
SMBJ48(C)A	MX	48	53.3	58.9	1	77.4	7.8	5
SMBJ51(C)A	MZ	51	56.7	52.7	1	82.4	7.3	5
SMBJ54(C)A	NE	54	60.0	66.3	1	87.1	6.9	5
SMBJ58(C)A	NG	58	64.4	71.2	1	93.6	6.4	5
SMBJ60(C)A	NK	60	66.7	73.7	1	96.8	6.2	5
SMBJ64(C)A	NM	64	71.1	78.6	1	103.0	5.8	5
SMBJ70(C)A	NP	70	77.8	86.0	1	113.0	5.3	5
SMBJ75(C)A	NR	75	83.3	92.1	1	121.0	5.0	5
SMBJ78(C)A	NT	78	86.7	95.8	1	126.0	4.8	5
SMBJ85(C)A	NV	85	94.4	104.0	1	137.0	4.4	5
SMBJ90(C)A	NX	90	100.0	111.0	1	146.0	4.1	5
SMBJ100(C)A	NZ	100	111.0	123.0	1	162.0	3.7	5
SMBJ110(C)A	PE	110	122.0	135.0	1	177.0	3.4	5
SMBJ120(C)A	PG	120	133.0	147.0	1	193.0	3.1	5
SMBJ130(C)A	PK	130	144.0	159.0	1	209.0	2.9	5
SMBJ150(C)A	PM	150	167.0	185.0	1	243.0	2.5	5
SMBJ160(C)A	PP	160	178.0	197.0	1	259.0	2.3	5
SMBJ170(C)A	PR	170	189.0	209.0	1	275.0	2.2	5

* Color band denotes cathode on unidirectional devices only. No color band on bidirectional devices.

** For bidirectional parts with V_{RWM} < 10V, the I_R max limit is doubled.

SMBJ5V0(C)A - SMBJ170(C)A

Transient Voltage Suppressors (continued)

Typical Characteristics

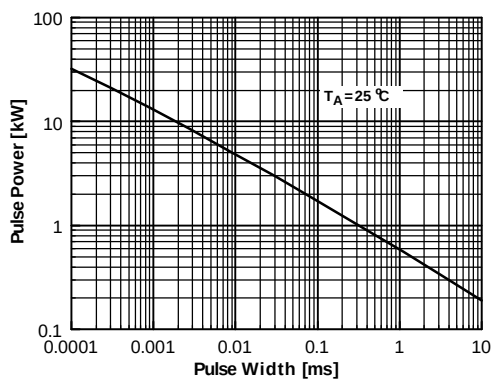


Figure 1. Peak Pulse Power Rating Curve

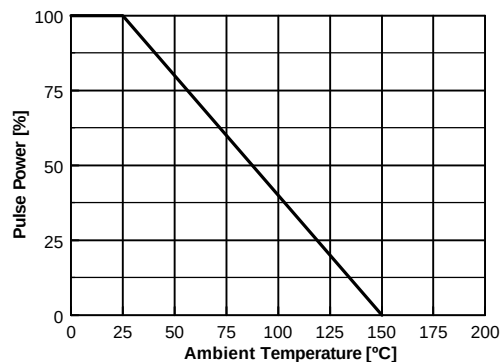


Figure 2. Pulse Derating Curve

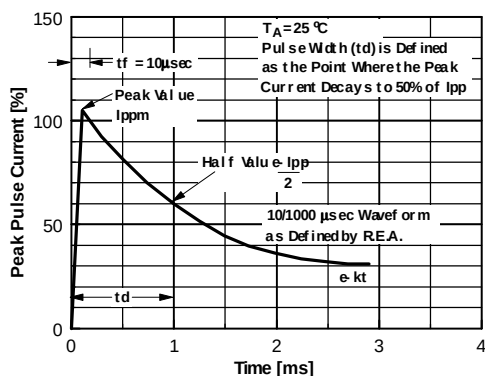


Figure 3. Pulse Waveform

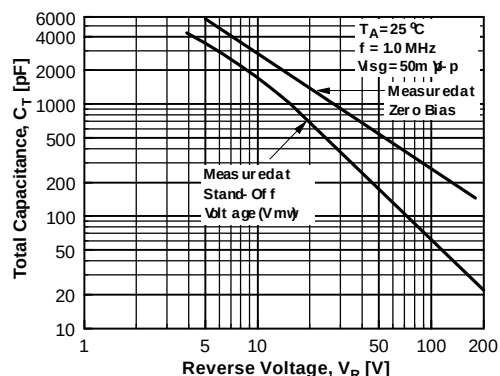


Figure 4. Total Capacitance

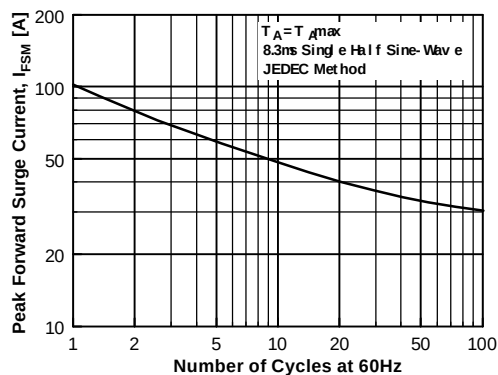


Figure 5. Non-Repetitive Surge Current

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